

HEF40240B

Octal inverting buffers with 3-state outputs

Rev. 5 — 15 November 2011

Product data sheet

1. General description

The HEF40240B is an octal inverting buffer with 3-state outputs. It features output stages with high current output capability suitable for driving highly capacitive loads.

The 3-state outputs are controlled by the output enable inputs $\overline{\text{nOE}}$. A HIGH on $\overline{\text{nOE}}$ causes the outputs to assume a high-impedance OFF-state. The device also features hysteresis on all inputs to improve noise immunity. Schmitt-trigger action makes the inputs highly tolerant to slow input rise and fall times.

The HEF40240B is pin and functionally compatible with the TTL '240' device.

It operates over a recommended V_{DD} power supply range of 3 V to 15 V referenced to V_{SS} (usually ground). Unused inputs must be connected to V_{DD} , V_{SS} , or another input.

2. Features and benefits

- Tolerant of slow input rise and fall times
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$
- Complies with JEDEC standard JESD 13-B

3. Ordering information

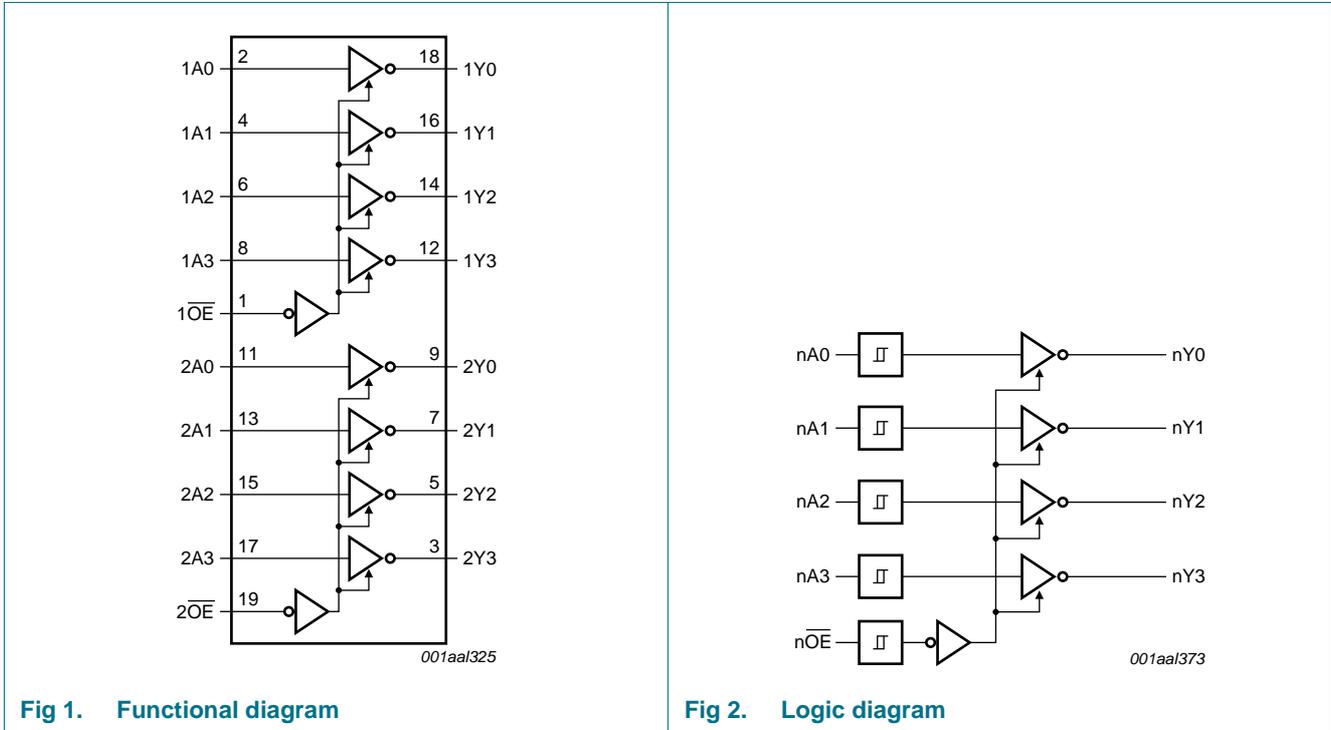
Table 1. Ordering information

All types operate from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$.

| Type number | Package | | Version |
|-------------|---------|--|----------|
| | Name | Description | |
| HEF40240BP | DIP20 | plastic dual in-line package; 20 leads (300 mil) | SOT146-1 |
| HEF40240BT | SO20 | plastic small outline package; 20 leads; body width 7.5 mm | SOT163-1 |

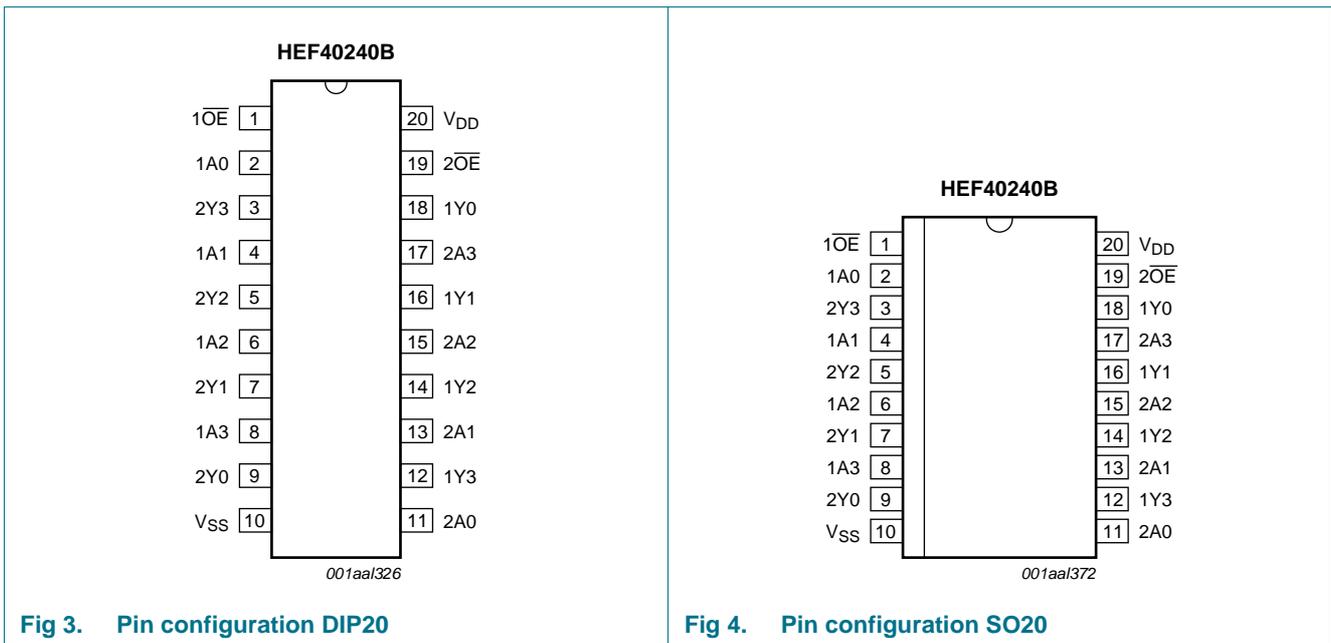


4. Functional diagram



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

| Symbol | Pin | Description |
|--------------------|----------------|----------------------------------|
| $1\overline{OE}$ | 1 | output enable input (active LOW) |
| 1A0, 1A1, 1A2, 1A3 | 2, 4, 6, 8 | data input |
| V_{SS} | 10 | ground (0 V) |
| 2Y0, 2Y1, 2Y2, 2Y3 | 9, 7, 5, 3 | data output |
| 2A0, 2A1, 2A2, 2A3 | 11, 13, 15, 17 | data input |
| V_{DD} | 20 | supply voltage |
| 1Y0, 1Y1, 1Y2, 1Y3 | 18, 16, 14, 12 | data output |
| $2\overline{OE}$ | 19 | output enable input (active LOW) |

6. Functional description

Table 3. Function table^[1]

| Inputs | | Output |
|--------|------------------|--------|
| nAn | \overline{nOE} | nYn |
| H | L | L |
| L | L | H |
| X | H | Z |

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------|--|------------------|----------------|------|
| V_{DD} | supply voltage | | -0.5 | +18 | V |
| I_{IK} | input clamping current | $V_I < -0.5\text{ V}$ or $V_I > V_{DD} + 0.5\text{ V}$ | - | ± 10 | mA |
| V_I | input voltage | | -0.5 | $V_{DD} + 0.5$ | V |
| I_{OK} | output clamping current | $V_O < -0.5\text{ V}$ or $V_O > V_{DD} + 0.5\text{ V}$ | - | ± 10 | mA |
| I_I | input leakage current | into any input | - | ± 10 | mA |
| I_O | output current | sink or source current | ^[1] - | ± 25 | mA |
| I_{DD} | supply current | to any supply terminal | - | ± 100 | mA |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| T_{amb} | ambient temperature | | -40 | +85 | °C |
| P_{tot} | total power dissipation | $T_{amb} = -40\text{ °C}$ to $+85\text{ °C}$ | | | |
| | | DIP20 package | ^[2] - | 750 | mW |
| | | SO20 package | ^[3] - | 500 | mW |
| P | power dissipation | per output | - | 100 | mW |

[1] See [Figure 6](#).

[2] For DIP20 package: P_{tot} derates linearly with 12 mW/K above 70 °C.

[3] For SO20 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

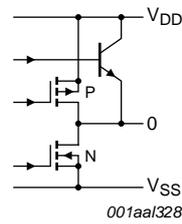
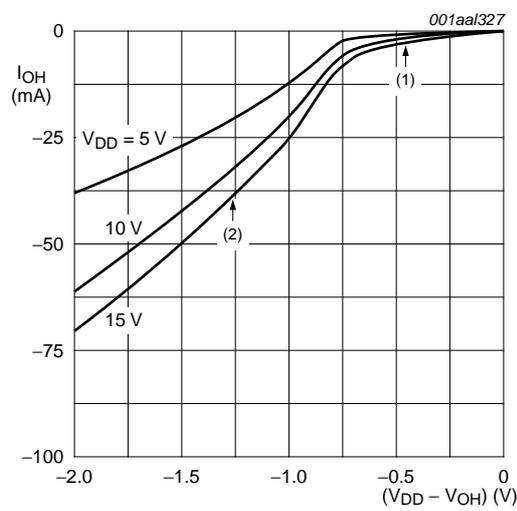


Fig 5. Schematic diagram of a buffer output stage



- (1) P-channel MOS transistor conducting.
- (2) P-channel MOS transistor and bipolar NPN transistor conducting.

Fig 6. Typical output source current characteristic

8. Recommended operating conditions

Table 5. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---------------------|-------------------------------------|------------------------|-----|-----|----------|-----------------|
| V_{DD} | supply voltage | | 3 | - | 15 | V |
| V_I | input voltage | | 0 | - | V_{DD} | V |
| T_{amb} | ambient temperature | in free air | -40 | - | +85 | °C |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{DD} = 5\text{ V}$ | - | - | 3.75 | $\mu\text{s/V}$ |
| | | $V_{DD} = 10\text{ V}$ | - | - | 0.5 | $\mu\text{s/V}$ |
| | | $V_{DD} = 15\text{ V}$ | - | - | 0.08 | $\mu\text{s/V}$ |

9. Static characteristics

Table 6. Static characteristics

$V_{SS} = 0\text{ V}$; $V_I = V_{SS}$ or V_{DD} unless otherwise specified.

| Symbol | Parameter | Conditions | V_{DD} | $T_{amb} = -40\text{ }^{\circ}\text{C}$ | | $T_{amb} = +25\text{ }^{\circ}\text{C}$ | | $T_{amb} = +85\text{ }^{\circ}\text{C}$ | | Unit |
|----------|---------------------------|--------------------------------|----------|---|-----------|---|-----------|---|-----------|---------------|
| | | | | Min | Max | Min | Max | Min | Max | |
| V_{IH} | HIGH-level input voltage | $ I_O < 1\text{ }\mu\text{A}$ | 5 V | 3.5 | - | 3.5 | - | 3.5 | - | V |
| | | | 10 V | 7.0 | - | 7.0 | - | 7.0 | - | V |
| | | | 15 V | 11.0 | - | 11.0 | - | 11.0 | - | V |
| V_{IL} | LOW-level input voltage | $ I_O < 1\text{ }\mu\text{A}$ | 5 V | - | 1.5 | - | 1.5 | - | 1.5 | V |
| | | | 10 V | - | 3.0 | - | 3.0 | - | 3.0 | V |
| | | | 15 V | - | 4.0 | - | 4.0 | - | 4.0 | V |
| V_H | hysteresis voltage | for any input | 5 V | - | - | - | 220.0 | - | - | mV |
| | | | 10 V | - | - | - | 250.0 | - | - | mV |
| | | | 15 V | - | - | - | 320.0 | - | - | mV |
| V_{OH} | HIGH-level output voltage | $ I_O < 1\text{ }\mu\text{A}$ | 5 V | 4.95 | - | 4.95 | - | 4.95 | - | V |
| | | | 10 V | 9.95 | - | 9.95 | - | 9.95 | - | V |
| | | | 15 V | 14.95 | - | 14.95 | - | 14.95 | - | V |
| V_{OL} | LOW-level output voltage | $ I_O < 1\text{ }\mu\text{A}$ | 5 V | - | 0.05 | - | 0.05 | - | 0.05 | V |
| | | | 10 V | - | 0.05 | - | 0.05 | - | 0.05 | V |
| | | | 15 V | - | 0.05 | - | 0.05 | - | 0.05 | V |
| I_{OH} | HIGH-level output current | $V_O = 3.6\text{ V}$ | 5 V | - | -9.3 | -24.0 | -10.0 | - | -10.7 | mA |
| | | $V_O = 8.4\text{ V}$ | 10 V | - | -14.4 | -46.0 | -15.0 | - | -15.0 | mA |
| | | $V_O = 13.2\text{ V}$ | 15 V | - | -19.5 | -62.0 | -20.0 | - | -19.8 | mA |
| | | $V_O = 4.6\text{ V}$ | 5 V | - | -0.75 | -1.2 | -0.6 | - | -0.45 | mA |
| | | $V_O = 9.5\text{ V}$ | 10 V | - | -1.85 | -3.0 | -1.5 | - | -1.1 | mA |
| | | $V_O = 13.5\text{ V}$ | 15 V | - | -14.5 | -50.0 | -15.0 | - | -15.5 | mA |
| I_{OL} | LOW-level output current | $V_O = 0.4\text{ V}$ | 5 V | 2.9 | - | 2.3 | 5.4 | 1.75 | - | mA |
| | | $V_O = 0.5\text{ V}$ | 10 V | 9.5 | - | 7.6 | 17.0 | 5.50 | - | mA |
| | | $V_O = 1.5\text{ V}$ | 15 V | 30.0 | - | 25.0 | 45.0 | 19.0 | - | mA |
| I_I | input leakage current | | 15 V | - | ± 0.3 | - | ± 0.3 | - | ± 1.0 | μA |
| I_{DD} | supply current | $I_O = 0\text{ A}$ | 5 V | - | 4 | - | 4 | - | 30 | μA |
| | | | 10 V | - | 8 | - | 8 | - | 60 | μA |
| | | | 15 V | - | 16 | - | 16 | - | 120 | μA |
| I_{OZ} | OFF-state output current | | 15 V | - | 1.6 | - | 1.6 | - | 12 | μA |
| C_I | input capacitance | | - | - | - | - | 7.5 | - | - | pF |

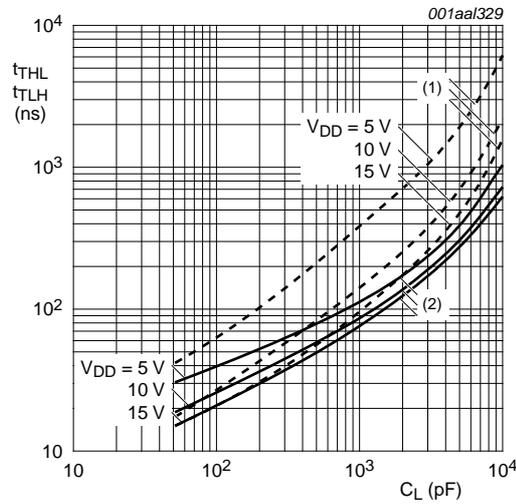
10. Dynamic characteristics

Table 7. Dynamic characteristics

$V_{SS} = 0\text{ V}$; $T_{amb} = 25\text{ °C}$; for test circuit see [Figure 10](#); unless otherwise specified.

| Symbol | Parameter | Conditions | V_{DD} | Extrapolation formula | Min | Typ | Max | Unit |
|------------------|-------------------------------------|--|----------|---|-----|-----|-----|------|
| t _{PHL} | HIGH to LOW propagation delay | nAn to nYn; see Figure 8 | 5 V | [1] $83\text{ ns} + (0.24\text{ ns/pF})C_L$ | - | 95 | 190 | ns |
| | | | 10 V | $35\text{ ns} + (0.10\text{ ns/pF})C_L$ | - | 40 | 80 | ns |
| | | | 15 V | $26\text{ ns} + (0.07\text{ ns/pF})C_L$ | - | 30 | 60 | ns |
| t _{PLH} | LOW to HIGH propagation delay | nAn to nYn; see Figure 8 | 5 V | [1] $82\text{ ns} + (0.06\text{ ns/pF})C_L$ | - | 85 | 170 | ns |
| | | | 10 V | $38\text{ ns} + (0.03\text{ ns/pF})C_L$ | - | 40 | 80 | ns |
| | | | 15 V | $29\text{ ns} + (0.02\text{ ns/pF})C_L$ | - | 30 | 60 | ns |
| t _{PHZ} | HIGH to OFF-state propagation delay | n $\overline{\text{OE}}$ to nYn; nYn is HIGH; see Figure 9 | 5 V | | - | 70 | 140 | ns |
| | | | 10 V | | - | 35 | 70 | ns |
| | | | 15 V | | - | 30 | 60 | ns |
| t _{PLZ} | LOW to OFF-state propagation delay | n $\overline{\text{OE}}$ to nYn; nYn is LOW; see Figure 9 | 5 V | | - | 75 | 150 | ns |
| | | | 10 V | | - | 40 | 80 | ns |
| | | | 15 V | | - | 30 | 60 | ns |
| t _{PZH} | OFF-state to HIGH propagation delay | n $\overline{\text{OE}}$ to nYn; nYn goes HIGH; see Figure 9 | 5 V | | - | 80 | 160 | ns |
| | | | 10 V | | - | 35 | 70 | ns |
| | | | 15 V | | - | 30 | 60 | ns |
| t _{PZL} | OFF-state to LOW propagation delay | n $\overline{\text{OE}}$ to nYn; nYn goes LOW; see Figure 9 | 5 V | | - | 90 | 180 | ns |
| | | | 10 V | | - | 40 | 80 | ns |
| | | | 15 V | | - | 30 | 60 | ns |
| t _{THL} | HIGH to LOW output transition time | see Figure 7 and Figure 8 | 5 V | | - | 40 | 80 | ns |
| | | | 10 V | | - | 20 | 40 | ns |
| | | | 15 V | | - | 15 | 30 | ns |
| t _{TLH} | LOW to HIGH output transition time | see Figure 7 and Figure 8 | 5 V | | - | 30 | 60 | ns |
| | | | 10 V | | - | 20 | 40 | ns |
| | | | 15 V | | - | 15 | 30 | ns |

[1] The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C_L in pF).



- (1) t_{THL} .
- (2) t_{TLH} .

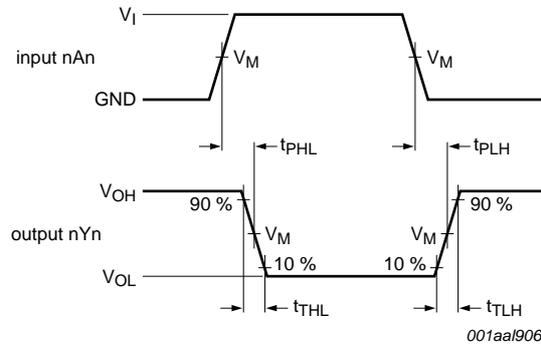
Fig 7. Output transition times as a function of the load capacitance

Table 8. Dynamic power dissipation P_D

P_D can be calculated from the formulas shown. $V_{SS} = 0 V$; $t_r = t_f \leq 20 ns$; $T_{amb} = 25 ^\circ C$.

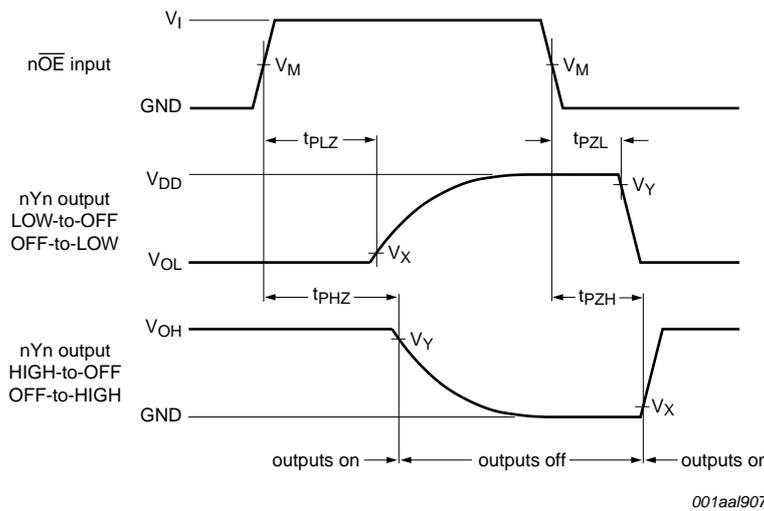
| Symbol | Parameter | V_{DD} | Typical formula for P_D (μW) | where: |
|--------|---------------------------|----------|---|---|
| P_D | dynamic power dissipation | 5 V | $P_D = 4250 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$ | f_i = input frequency in MHz, |
| | | 10 V | $P_D = 17000 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$ | f_o = output frequency in MHz, |
| | | 15 V | $P_D = 46000 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$ | C_L = output load capacitance in pF, V_{DD} = supply voltage in V, $\Sigma(f_o \times C_L)$ = sum of the outputs. |

11. Waveforms



Measurement points are given in Table 9, V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 8. Waveforms showing propagation and transition delays

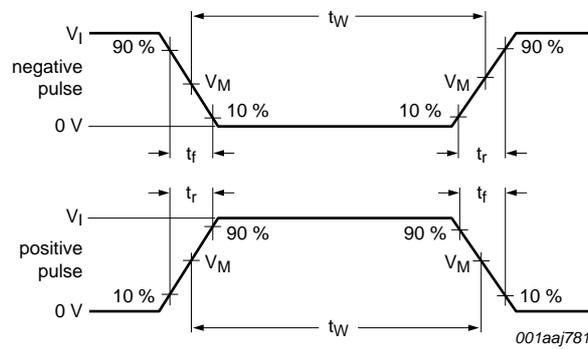


Measurement points are given in Table 9, V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

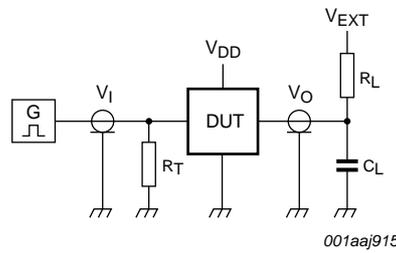
Fig 9. 3-state enable and disable times

Table 9. Measurement points

| Supply voltage | Input | Output | | |
|----------------|-------------|-------------|-------------|-------------|
| V_{DD} | V_M | V_M | V_X | V_Y |
| 5 V to 15 V | $0.5V_{DD}$ | $0.5V_{DD}$ | $0.1V_{DD}$ | $0.9V_{DD}$ |



a. Input waveforms



b. Test circuit

For test data see [Table 10](#).

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance.

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

Fig 10. Test circuit for measuring switching times

Table 10. Test data

| Supply voltage | Input | | Load | | V_{EXT} | | |
|----------------|----------------------|--------------|-------|--------------|--------------------|--------------------|--------------------|
| V_{DD} | V_I | t_r, t_f | C_L | R_L | t_{PLH}, t_{PHL} | t_{PLZ}, t_{PZL} | t_{PHZ}, t_{PZH} |
| 5 V to 15 V | V_{SS} or V_{DD} | ≤ 20 ns | 50 pF | 1 k Ω | open | V_{DD} | GND |

12. Package outline

DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1

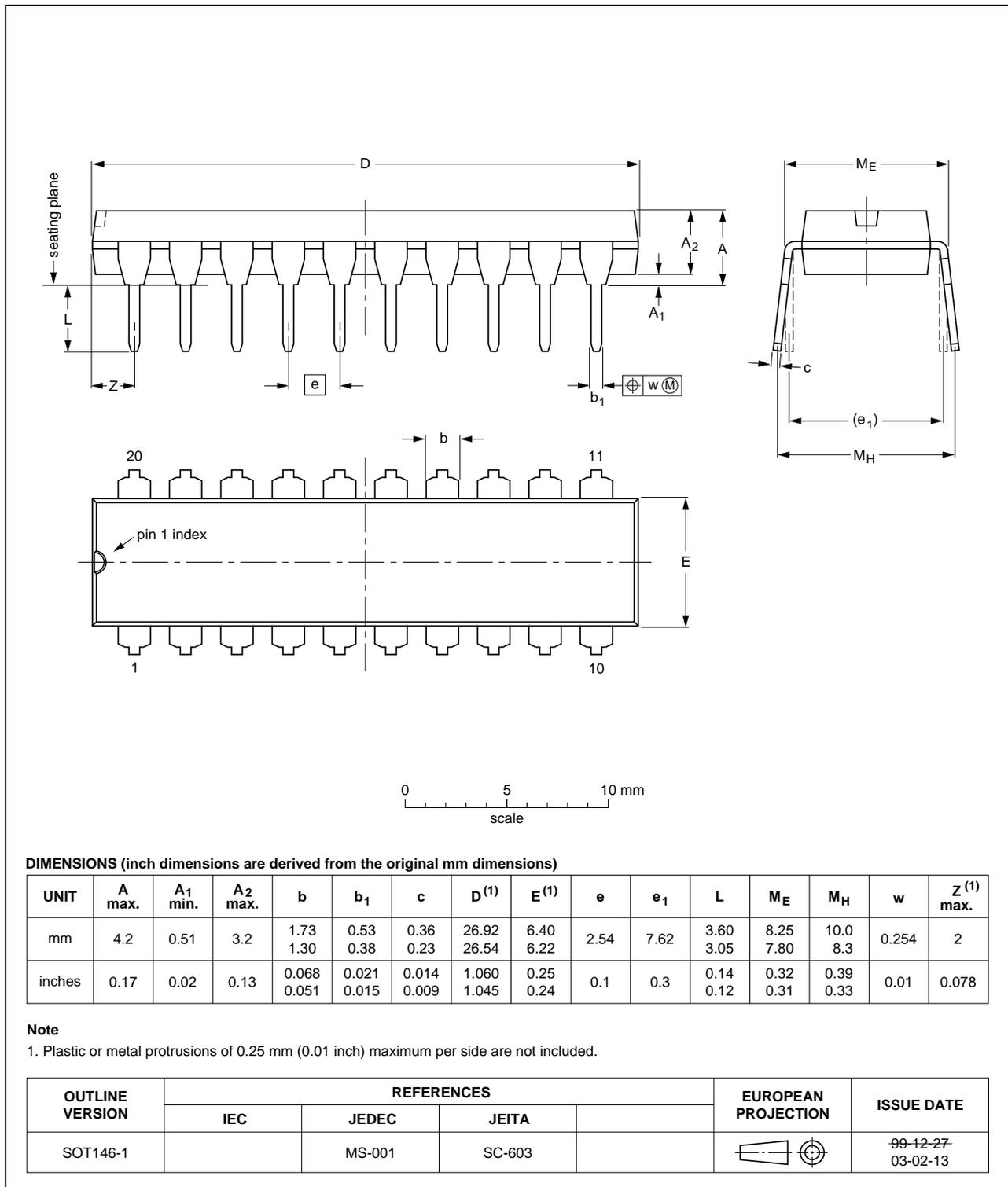


Fig 11. Package outline SOT146-1 (DIP20)

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1

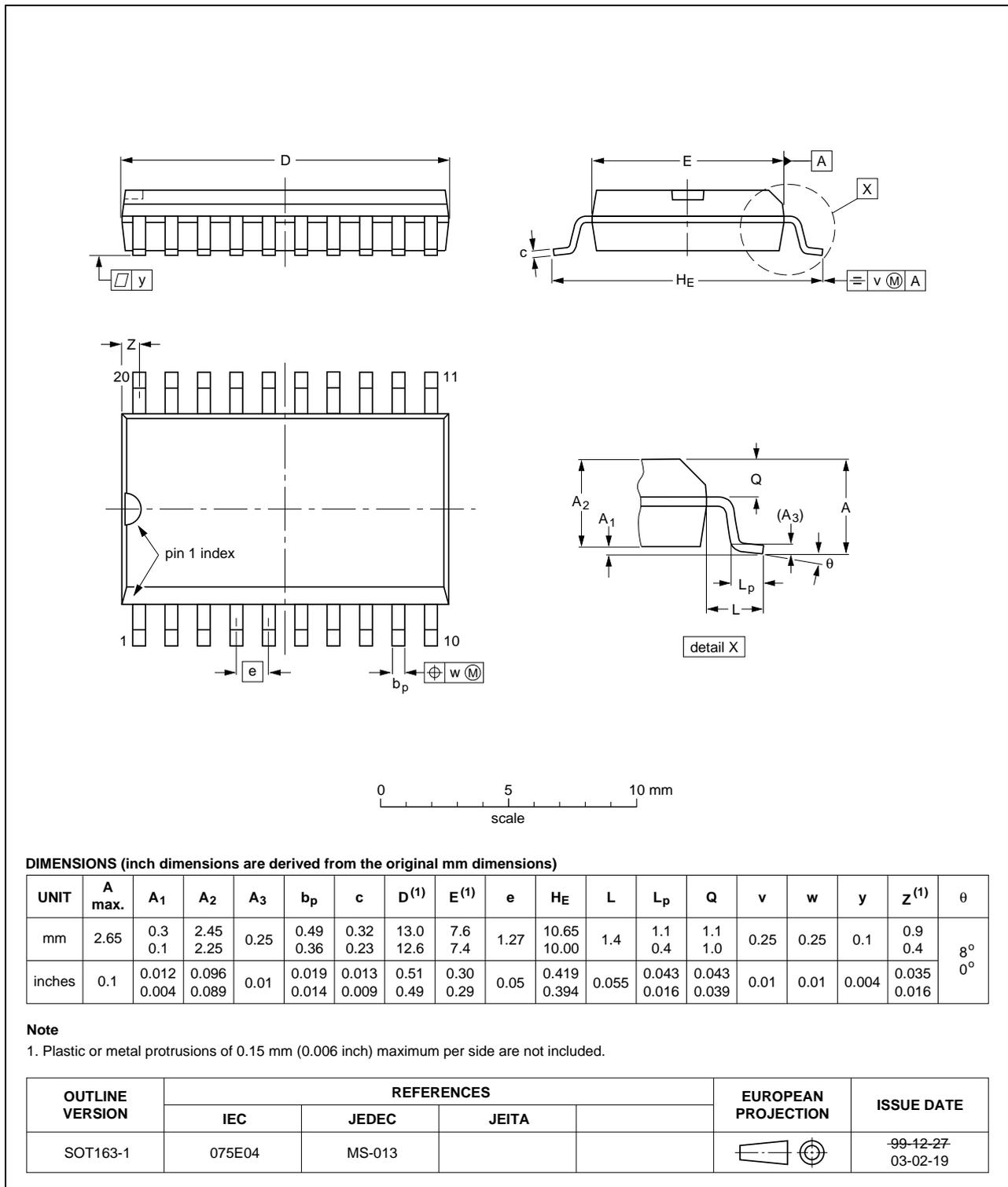


Fig 12. Package outline SOT163-1 (SO20)

13. Abbreviations

Table 11. Abbreviations

| Acronym | Description |
|---------|-----------------------------|
| DUT | Device Under Test |
| MOS | Metal Oxide Semiconductor |
| TTL | Transistor-Transistor Logic |

14. Revision history

Table 12. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|-------------------|--|-----------------------|---------------|-------------------|
| HEF40240B v.5 | 20111115 | Product data sheet | - | HEF40240B v.4 |
| Modifications: | <ul style="list-style-type: none">• Section Applications removed• Table 6: I_{OH} minimum values changed to maximum | | | |
| HEF40240B v.4 | 20100420 | Product data sheet | - | HEF40240B_CNV v.3 |
| HEF40240B_CNV v.3 | 19950101 | Product specification | - | HEF40240B_CNV v.2 |
| HEF40240B_CNV v.2 | 19950101 | Product specification | - | - |

15. Legal information

15.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
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| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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